

TOSHIBA

TC74LCX574F/FW/FT

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LCX574F, TC74LCX574FW, TC74LCX574FT

LOW VOLTAGE OCTAL D-TYPE FLIP-FLOP WITH 5V TOLERANT INPUTS AND OUTPUTS

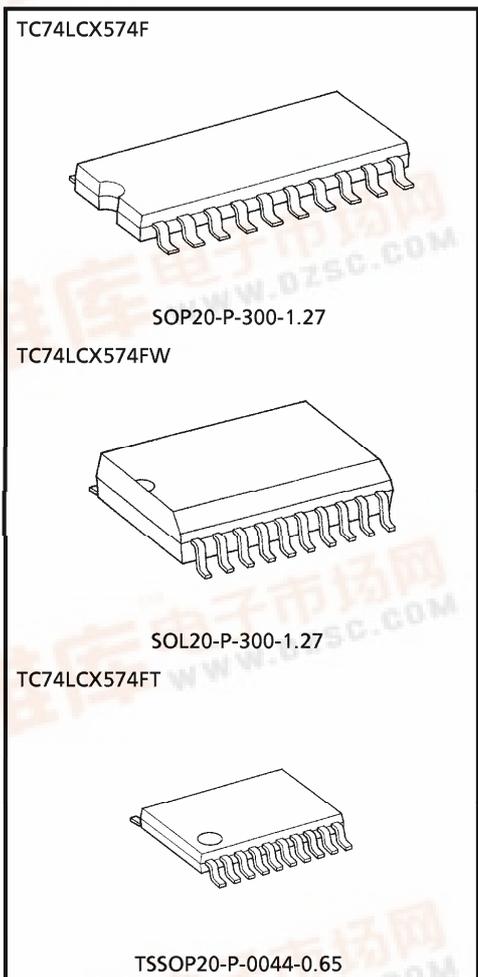
The TC74LCX574 is a high performance CMOS OCTAL D-TYPE FLIP FLOP. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3V) V_{CC} applications, but it could be used to interface to 5V supply environment for both inputs and outputs.

This 8bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge.

(Note) The JEDEC SOP (FW) is not available in Japan.



FEATURES

- Low voltage operation : $V_{CC} = 2.0 \sim 3.6V$
- High speed operation : $t_{pd} = 8.5ns$ (Max.)
($V_{CC} = 3.0 \sim 3.6V$)
- Output current : $|I_{OH}| / |I_{OL}| = 24mA$ (Min.)
($V_{CC} = 3.0V$)
- Latch-up performance : $\pm 500mA$
- Available in JEDEC SOP, EIAJ SOP and TSSOP
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 574 type.

Weight

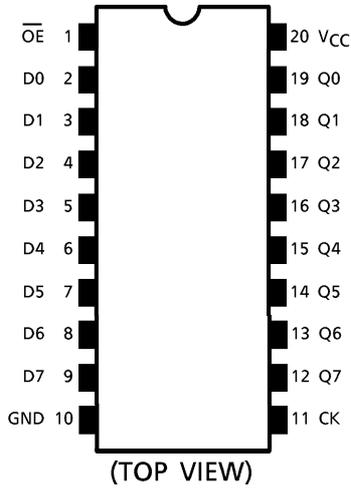
- SOP20-P-300-1.27 : 0.22g (Typ.)
- SOL20-P-300-1.27 : 0.46g (Typ.)
- TSSOP20-P-0044-0.65 : 0.08g (Typ.)

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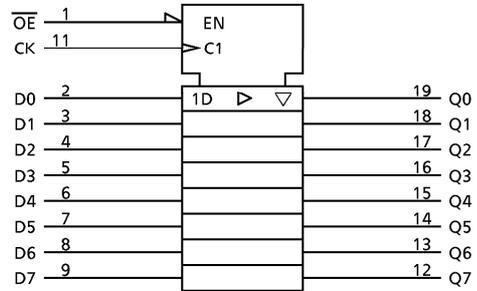
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PIN ASSIGNMENT



IEC LOGIC SYMBOL

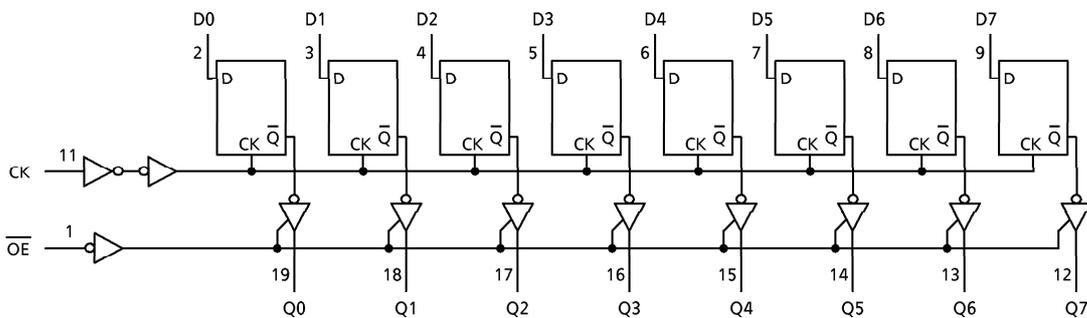


TRUTH TABLE

INPUTS			OUTPUTS
\overline{OE}	CK	D	
H	X	X	Z
L	\downarrow	X	Qn
L	\uparrow	L	L
L	\uparrow	H	H

X : Don't Care
 Z : High Impedance
 Qn : No change

SYSTEM DIAGRAM



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MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~7.0 (Note 1)	V
		-0.5~ V_{CC} +0.5 (Note 2)	
Input Diode Current	I_{IK}	-50	mA
Output Diode Current	I_{OK}	±50 (Note 3)	mA
DC Output Current	I_{OUT}	±50	mA
Power Dissipation	P_D	180	mW
DC V_{CC} /Ground Current	I_{CC}/I_{GND}	±100	mA
Storage Temperature	T_{stg}	-65~150	°C

(Note 1) Output in Off-State

(Note 2) High or Low State. I_{OUT} absolute maximum rating must be observed.

(Note 3) $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
		1.5~3.6 (Note 4)	
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH}/I_{OL}	±24 (Note 7)	mA
		±12 (Note 8)	
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 9)	ns/V

(Note 4) Data Retention Only

(Note 5) Output in Off-State

(Note 6) High or Low State

(Note 7) $V_{CC} = 3.0\sim 3.6V$

(Note 8) $V_{CC} = 2.7\sim 3.0V$

(Note 9) $V_{IN} = 0.8\sim 2.0V$, $V_{CC} = 3.0V$

ELECTRICAL CHARACTERISTICS
 DC CHARACTERISTICS (Ta = -40~85°C)

PARAMETER		SYMBOL	TEST CONDITION	V _{CC} (V)	MIN.	MAX.	UNIT	
Input Voltage	"H" Level	V _{IH}		2.7~3.6	2.0	—	V	
	"L" Level	V _{IL}		2.7~3.6	—	0.8		
Output Voltage	"H" Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100μA	2.7~3.6	V _{CC} - 0.2	—	V
				I _{OH} = -12mA	2.7	2.2	—	
				I _{OH} = -18mA	3.0	2.4	—	
				I _{OH} = -24mA	3.0	2.2	—	
	"L" Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100μA	2.7~3.6	—	0.2	
				I _{OL} = 12mA	2.7	—	0.4	
				I _{OL} = 16mA	3.0	—	0.4	
				I _{OL} = 24mA	3.0	—	0.55	
Input Leakage Current		I _{IN}	V _{IN} = 0~5.5V	2.7~3.6	—	±5.0	μA	
3-State Output Off-State Current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0~5.5V	2.7~3.6	—	±5.0	μA	
Power Off Leakage Current		I _{OFF}	V _{IN} / V _{OUT} = 5.5V	0	—	10.0	μA	
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND	2.7~3.6	—	10.0	μA	
			V _{IN} / V _{OUT} = 3.6~5.5V	2.7~3.6	—	±10.0		
Increase In I _{CC} Per Input		ΔI _{CC}	V _{IH} = V _{CC} - 0.6V	2.7~3.6	—	500	μA	

AC CHARACTERISTICS (Ta = -40~85°C)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	MIN.	MAX.	UNIT
Maximum Clock Frequency	f _{MAX}	(Fig.1, 2)	2.7	—	—	MHz
			3.3 ± 0.3	150	—	
Propagation Delay Time (CK-Q)	t _{pLH}	(Fig.1, 2)	2.7	—	9.5	ns
	t _{pHL}		3.3 ± 0.3	1.5	8.5	
Output Enable Time	t _{pZL}	(Fig.1, 3)	2.7	—	9.5	ns
	t _{pZH}		3.3 ± 0.3	1.5	8.5	
Output Disable Time	t _{pLZ}	(Fig.1, 3)	2.7	—	7.0	ns
	t _{pHZ}		3.3 ± 0.3	1.5	6.5	
Minimum Pulse Width (CK)	t _w (H)	(Fig.1, 2)	2.7	3.3	—	ns
	t _w (L)		3.3 ± 0.3	3.3	—	
Minimum Set-Up Time	t _s	(Fig.1, 2)	2.7	2.5	—	ns
			3.3 ± 0.3	2.5	—	
Minimum Hold Time	t _h	(Fig.1, 2)	2.7	1.5	—	ns
			3.3 ± 0.3	1.5	—	
Output To Output Skew	t _{osLH}	(Note 10)	2.7	—	—	ns
	t _{osHL}		3.3 ± 0.3	—	1.0	

(Note 10) Parameter guaranteed by design.
 (t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)

DYNAMIC SWITCHING CHARACTERISTICS (Ta = 25°C, Input t_r = t_f = 2.5ns, C_L = 50pF, R_L = 500Ω)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V

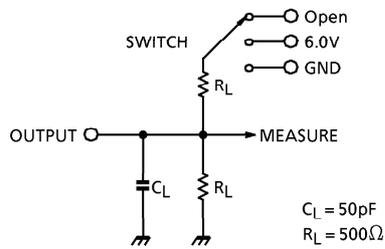
CAPACITIVE CHARACTERISTICS (Ta = 25°C)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	UNIT
Input Capacitance	C _{IN}	—	3.3	7	pF
Output Capacitance	C _{OUT}		3.3	8	pF
Power Dissipation Capacitance	C _{PD}	f _{IN} = 10MHz (Note 11)	3.3	25	pF

(Note 11) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.
 Average operating current can be obtained by the equation :
 I_{CC (opr.)} = C_{PD} · V_{CC} · f_{IN} + I_{CC} / 8 (per bit)

TEST CIRCUIT

Fig.1



PARAMETER	SWITCH
t_{pLH} , t_{pHL}	Open
t_{pLZ} , t_{pZL}	6.0V
t_{pHZ} , t_{pZH}	GND
t_w , t_s , t_h , f_{MAX}	Open

AC WAVEFORM

Fig.2 t_{pLH} , t_{pHL} , t_w , t_s , t_h

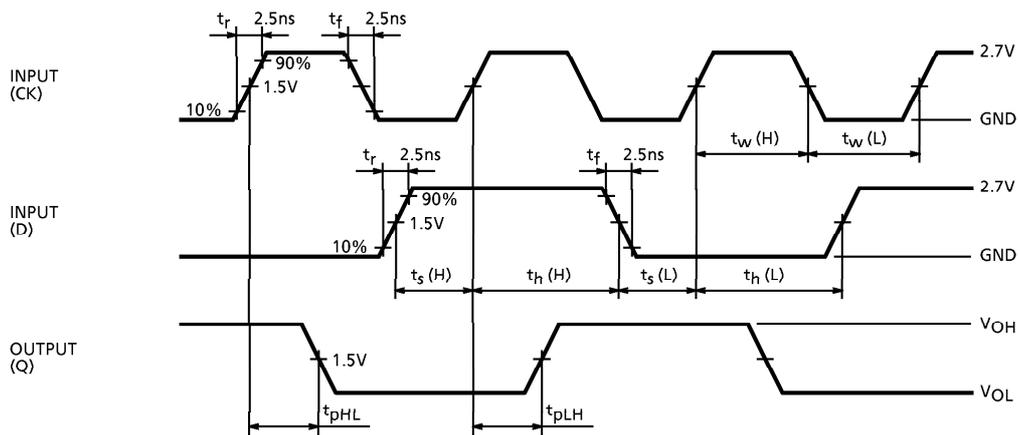
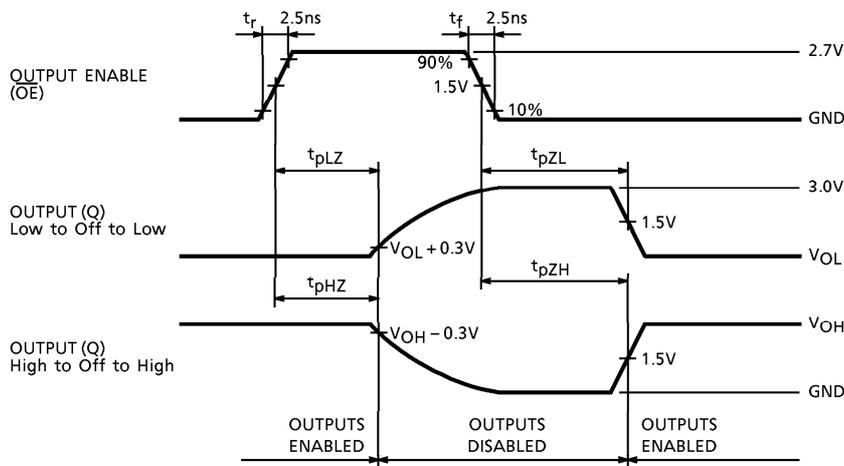
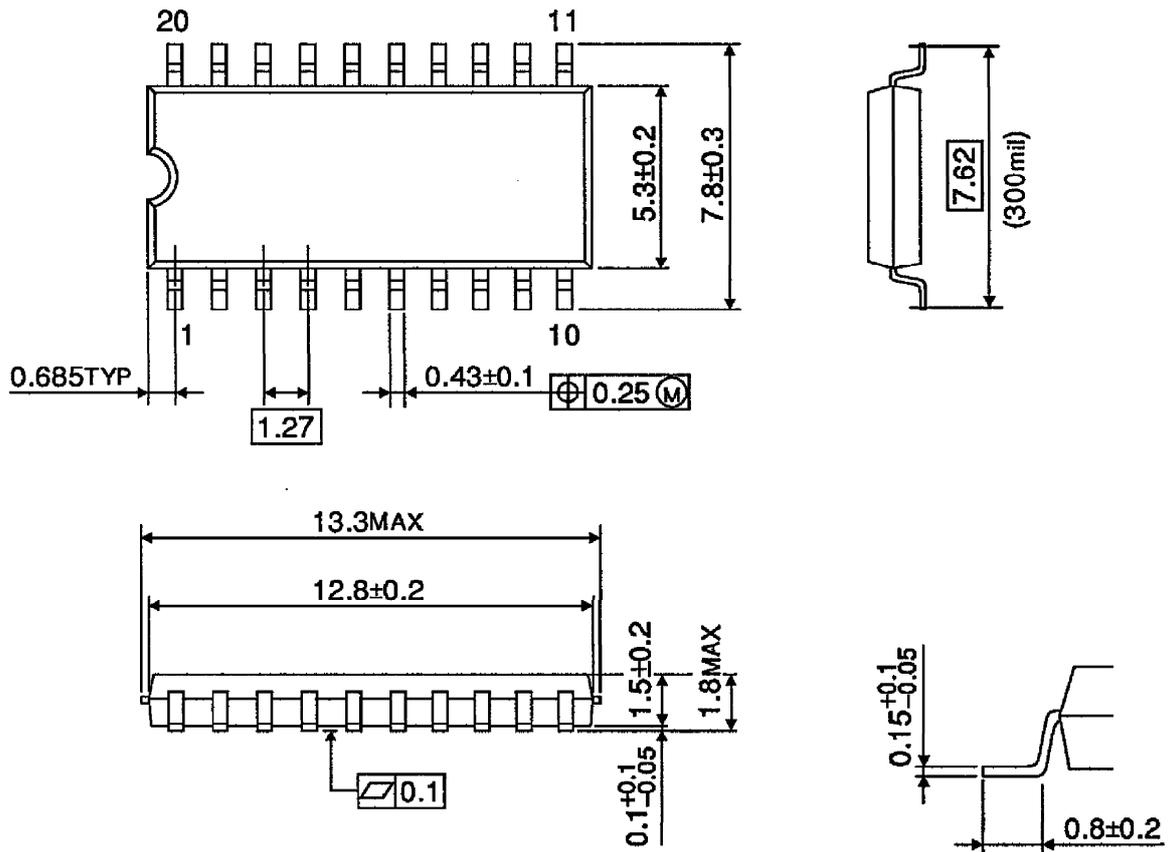


Fig.3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}



OUTLINE DRAWING
SOP20-P-300-1.27

Unit : mm

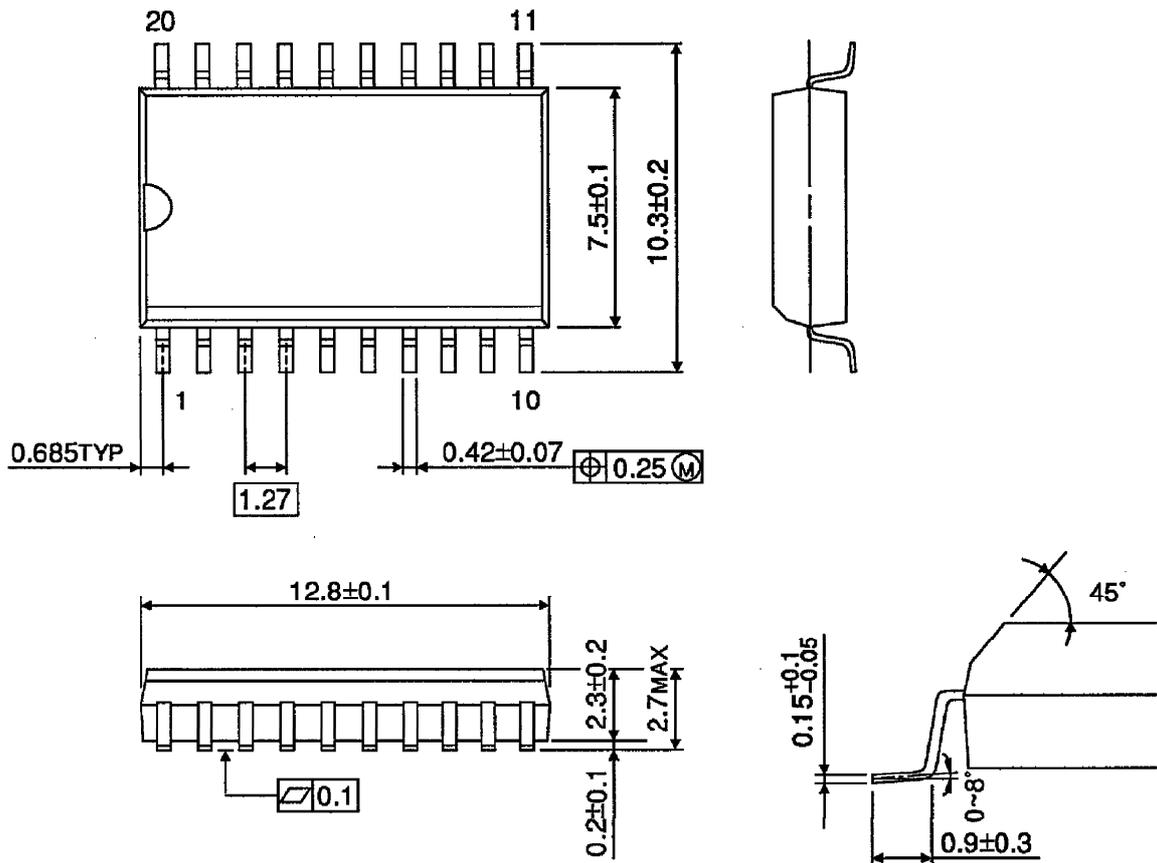


Weight : 0.22g (Typ.)

OUTLINE DRAWING
SOL20-P-300-1.27

Unit : mm

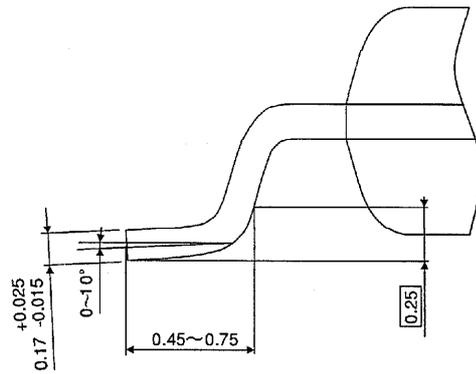
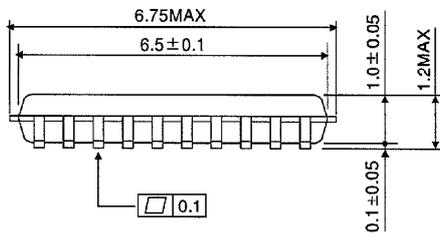
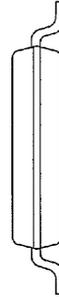
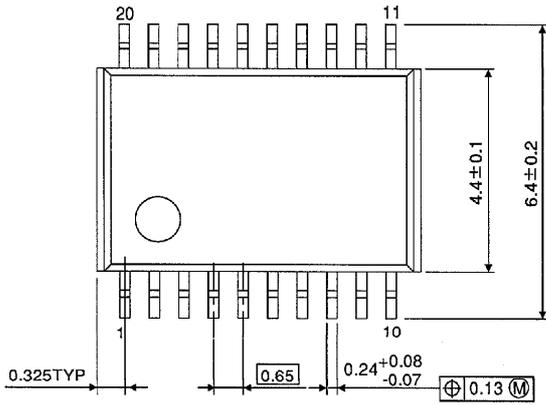
(Note) This package is not available in Japan.



Weight : 0.46g (Typ.)

OUTLINE DRAWING
TSSOP20-P-0044-0.65

Unit : mm



Weight : 0.08g (Typ.)